<u>Constructing the PWL</u> <u>Junction Diode Model</u>

Q: Wait a minute! How the heck are we supposed to use the **PWL model** to analyze junction diode circuits? **You** have yet to tell us the numeric **values** of voltage source V_{DO} and resistor r_d !

A: That's right! The reason is that the **proper** values of voltage source V_{DO} and resistor r_d are up to **you** to determine! To see why, consider the current voltage relationship of the **PWL model**:

$$i_{D} = \begin{cases} 0 & \text{for } v_{D} < V_{D0} \\ \left(\frac{1}{r_{d}}\right)v_{D} - \left(\frac{V_{D0}}{r_{d}}\right) & \text{for } v_{D} > V_{D0} \end{cases}$$

VD

VDO

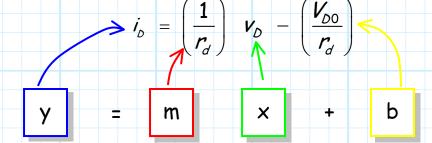
 $\frac{1}{r_{d}}$

+

VD

 V_{D0}

Note that when the **ideal** diode in the PWL model is forward biased, the current-voltage relationship is simply the equation of a **line**!

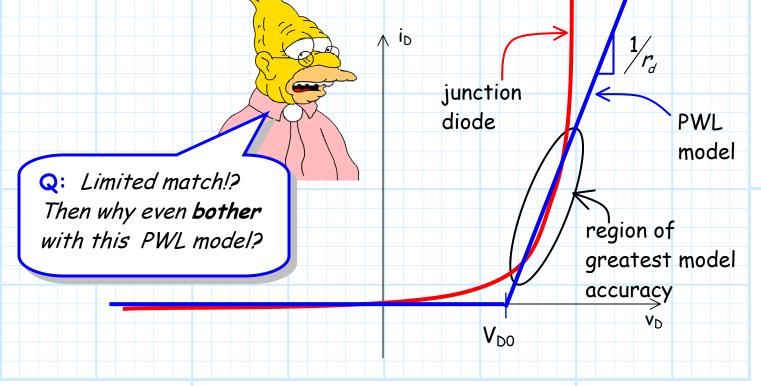


Compare the above to the forward biased junction diode approximation:

$$i_D = I_s e^{v_D/nV_T}$$

An exponential equation!

An exponential function and the equation of a line are **very** different—the two functions can approximately "match" only over a **limited** region:



A: Remember, the PWL model is **more accurate** than our two **alternatives**—the ideal diode model and the CVD model.

At the very least, the PWL model (unlike the two alternatives) shows an increasing voltage v_D with increasing i_D . Moreover, if we select the values of V_{DO} and r_d properly, the PWL can very accurately "match" the actual (exponential) junction diode curve over a decade or more of current (e.g., accurate from i_D = 1 mA to 10 mA, or from i_D = 20mA to 200mA).

Q: Yes well I asked you a long time ago what r_d and V_{DO} should be, but you **still** have not given me an **answer**!

A: OK. We now know that the values of r_d and V_{DO} specify a line. We also know there are **4** potential ways to **specify** a line:

- 1. Specify two points on the line.
- 2. Specify one **point** on the line, as well as its **slope** *m*.
- Specify one point on the line, as well as its yintercept b.
- 4. Specify both its slope and its y-intercept b.

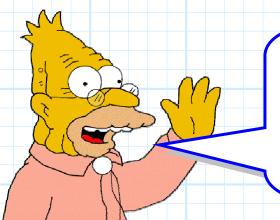
We will find that the **first two** methods are the most useful. Let's address them one at a time.

1. Specify two points on the line

The obvious question here is: Which two points?

Hopefully it is **equally** obvious that the two points should be points lying on the **junction diode** exponential curve (after all, it is this curve that we are **attempting to approximate**!).

Typically, we pick two current values separated by about a decade (i.e., 10 times). For example, we might select i_{D1} =10 mA and i_{D2} =100 mA. We will find that the resulting PWL model will be fairly accurate over this region.

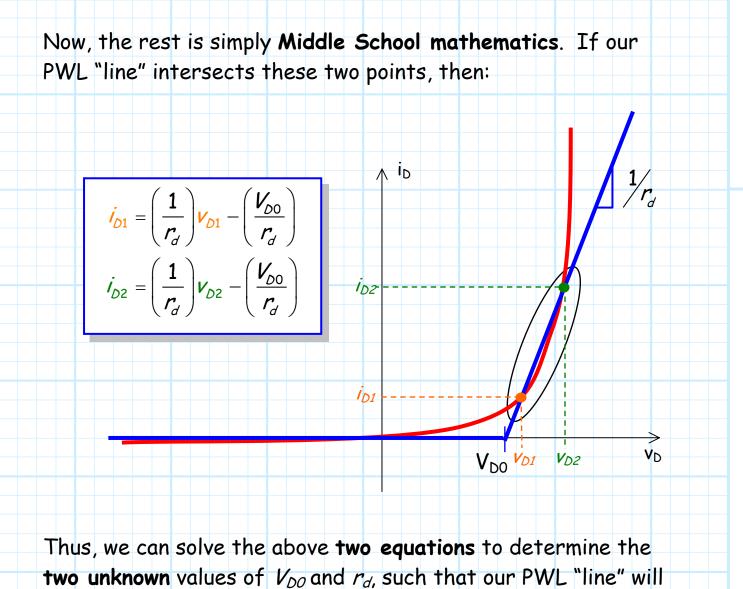


Q: I've got a question! How do we find the corresponding voltage values v_{D1} and v_{D2} for these two currents?

A: Remember, we are selecting two points on the exponential junction diode curve. Thus, we can use the junction diode equation to determine the corresponding voltages:

$$v_{D1} = nV_T \ln \left[\frac{I_{D1}}{I_s} \right]$$
$$v_{D2} = nV_T \ln \left[\frac{I_{D2}}{I_s} \right]$$

г.



intersect the two specified points on the junction diode curve:

$$m = \frac{1}{r_d} = \frac{i_{D2} - i_{D1}}{v_{D2} - v_{D1}} \qquad \therefore \qquad r_d = \frac{v_{D2} - v_{D1}}{i_{D2} - i_{D1}}$$

And then we use our PWL "line" equation to find r_d :

$$V_{D0} = V_{D1} - i_{D1} r_d$$
 or $V_{D0} = V_{D2} - i_{D2} r_d$

(note these two equations are KVL!).

Jim Stiles

2. Specify one point and the slope

Now let's examine **another** way of constructing our PWL model. We first specify just **one** point that the PWL "line" must intersect. Let's denote this point as (I_D, V_D) and call this point our **bias point**.

Of course, we want our bias point to **lie on** the exponential junction diode curve, i.e.:

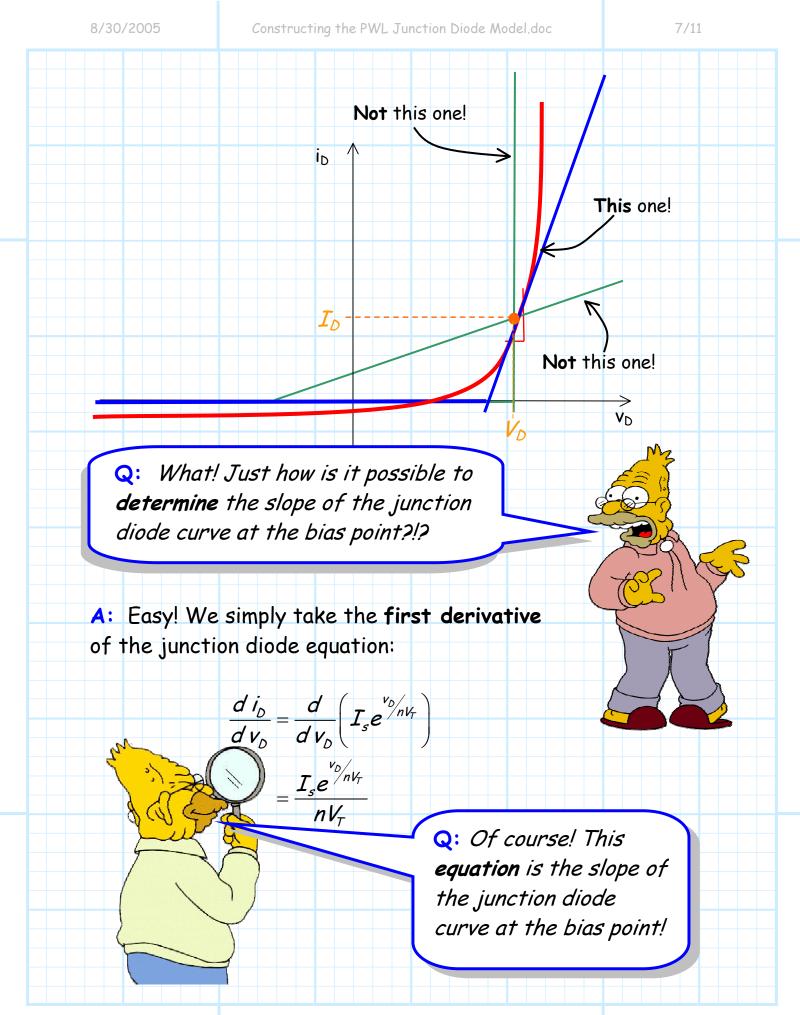
$$I_{D} = I_{s}e^{\frac{V_{D}}{nV_{T}}}$$
 or equivalently $V_{D} = nV_{T} \ln \left| \frac{I_{D}}{I_{s}} \right|$

Now, instead of specifying a second intersection point, we merely specify directly the PWL line slope (i.e., directly specify the value of r_d !):

 $m=\frac{1}{r_d}$

Q: But I have **no idea** what the value of this slope should be!?!

A: Think about it. Of all possible PWL models that intersect the bias point, the one that is most accurate is the one that has a slope **equal** to the slope of the exponential junction diode curve (that is, **at** the bias point)!

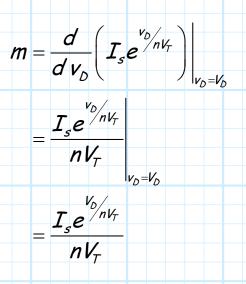


A: Actually no. The above equation is not the slope of the junction diode curve at the bias point. This equation provides the slope of the curve as a function diode voltage v_D . The slope of the junction diode curve is in fact different at every point on the junction diode curve.

In fact, as the equation above clearly states, the slope of the junction diode curve **exponential increases** with increasing v_D !

Q: Yikes! So what is the derivate equation good for?

A: Remember, we are interested in the value of the slope of the curve at one particular point—the bias point. Thus, we simply evaluate the derivative function at that point. The result is a numeric value of the slope at our bias point!



Note the **numerator** of this result! We recognize this numerator as simply the value of the **bias current** I_D :

$$I_D = I_s e^{V_D/nV_T}$$

$$m = \frac{I_{s}e^{\frac{V_{D}}{nV_{T}}}}{nV_{T}} = \frac{I_{D}}{nV_{T}}$$

Now, we want the slope of our **PWL model** line to be **equal** to the slope of the **junction diode curve** at our bias point. Therefore, we desire:

$$\frac{1}{r_d} = m = \frac{I_D}{nV_T}$$

Thus, **rearranging** this equation, we find that the PWL model **resistor value** should be:

 $r_{d} = \frac{nV_{T}}{I_{D}}$

We likewise can rearrange the PWL "line" equation to determine the value of the model voltage source
$$V_{DO}$$
:

$$V_{D0} = V_D - I_D r_d \qquad (KVL !)$$

Now, combining the previous two equations, we find:

$$V_{D0} = V_D - I_D r_d$$
$$= V_D - I_D \left(\frac{nV_T}{I_D}\right)$$
$$= V_D - nV_T$$

So, let's **recap** what we have learned about constructing a PWL model using this particular approach.

1. We first select a single **bias point** (I_D, V_D) , a point that lies on the junction diode curve, i.e.:

$$I_{D} = I_{s}e^{V_{D}/nV_{T}}$$

2. Using the current and voltage values of this bias point, we can then determine **directly** the PWL model **resistor value**:

$$r_{d} = \frac{nV_{T}}{I_{D}}$$

3. We can also directly determine the value of the model voltage source:

$$V_{D0} = V_D - n V_T$$

This method for constructing a **PWL model** produces a very **precise** match over a relatively small region of the junction diode curve.

We will find that this is very useful for many practical diode circuit problems and analysis!

This PWL model produced by this last method (as described by the equations of the previous page) is called the junction diode small-signal model.

We will use the *small-signal model* again—make sure that you know what it is and how we construct it!